Ref #	Hits	Search Query	DBs	Default Operato r	Plural s	Time Stamp
L1	133960	(zirconia (zirconium near5 (oxide dioxide)) hafina (hafnium near5 (oxide dioxide)))	US-PGPU B; USPAT; USOCR	OR	ON	2005/05/15 08:03
L2	22569	1 and (amorphous amorphize amorphizing amorphization)	US-PGPU B; USPAT; USOCR	OR	ON	2005/05/15 08:03
L3	5366	2 and ((amorphous amorphize amorphize amorphizing amorphization) same (zirconia (zirconium near5 (oxide dioxide)) hafina (hafnium near5 (oxide dioxide))))	US-PGPU B; USPAT; USOCR	OR	ON	2005/05/15 07:58
L4	301	2 and (((amorphous amorphize amorphize amorphizing amorphization) same (zirconia (zirconium near5 (oxide dioxide)) hafina (hafnium near5 (oxide dioxide))) same (etch\$3 pattern\$3)))	US-PGPU B; USPAT; USOCR	OR	ON	2005/05/15 07:59
L5	4	4 and (nondopant (heavy near5 (atom ion dopant)))	US-PGPU B; USPAT; USOCR	OR	ON	2005/05/15 08:01
L6	244	4 and (nondopant silicon germanium Ge Si argon Ar xenon Xe (heavy near5 (atom ion dopant)))	US-PGPU B; USPAT; USOCR	OR	ON	2005/05/15 08:04
L7	64451	(zirconia (zirconium near5 (oxide dioxide)) hafina (hafnium near5 (oxide dioxide)))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/15 08:03
L8	1362	7 and (amorphous amorphize amorphizing amorphization)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/15 08:03
L9	617	8 and (nondopant silicon germanium Ge Si argon Ar xenon Xe (heavy near5 (atom ion dopant)))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/15 08:04
L10	27	9 and gate	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/15 08:05

L11	20	10 and (insulat\$3 dielectric)	EPO; JPO; DERWENT	OR	ON	2005/05/15 08:06
			; IBM_TDB			